

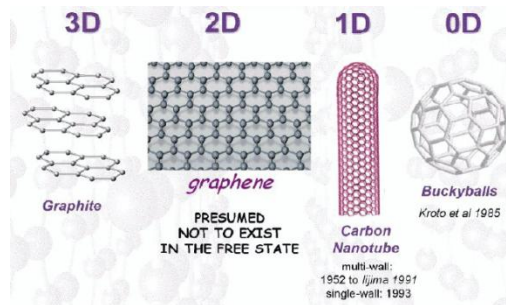
Graphene-based Thermal Interface Materials

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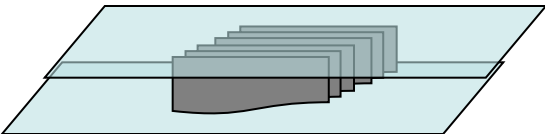
OBJECTIVE

Develop graphene based thermal interface materials (TIMs) that can enhance the TIM performances.

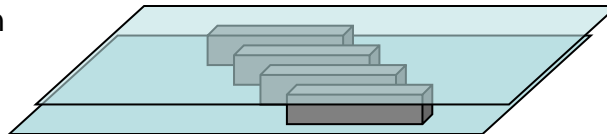


APPROACH

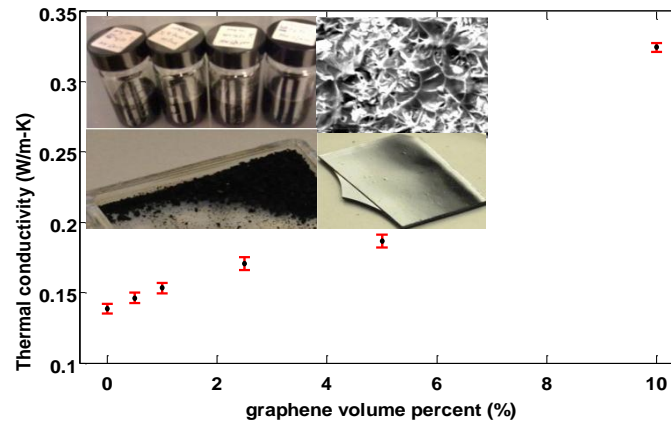
- Approach 1: Vertically grown (CVD) graphene sheets between (and bonded to) substrates



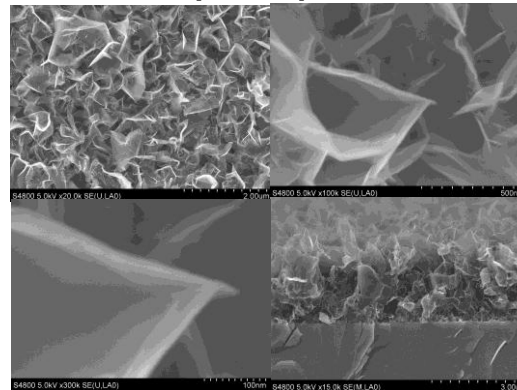
- Approach 2: Graphene composite/Graphite micro platelets/powder between substrates



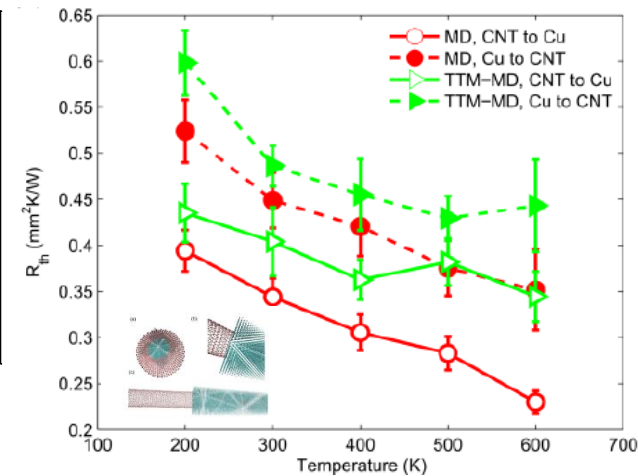
Graphene composite thermal conductivity



Graphene petals



Cu-CNT interface simulation



IMPACT

- Thermal conductivity can be dramatically enhanced by adding graphene fillers.
- Thermal interface between SiO_2 and graphene petals grown on silicon and copper by MPCVD is characterized by 3 ω method and the thermal interface resistance is estimated to be as low as 1.2 – 3.2 $\text{mm}^2\text{K/W}$.

PUBLICATIONS

- J.N. Hu, W. Park, X.L. Ruan and Y. P. Chen, Proceedings of MRS Spring Meeting (2012).
- Y. Wang, S.Y. Chen, and X.L. Ruan, Appl. Phys. Lett., **100**, 163101 (2012).
- J.N. Hu, Y. Wang, A. Vallabhaneni, X.L. Ruan, and Y.P. Chen, Appl. Phys. Lett., **99**, 113101 (2012).